## K. J. Somaiya Institute of Technology, Sion, Mumbai-22 (Autonomous College Affiliated to University of Mumbai)



Nov - Dec 2023

(B.Tech ) Program: EXTC Scheme: II

Examination: SY Semester: III

Course Code: EXC303 and Course Name: Electronic Devices and Circuits

Date of Exam: 04/12/2023 Duration: 2.5 Hours Instructions: Max. Marks: 60 (1)All questions are compulsory.

(2)Draw neat diagrams wherever applicable.

(3) Assume suitable data, if necessary. Max. CO BT Marks level Solve any six questions out of eight. 01 12 Sketch P-N junction showing depletion region. Briefly explain how i) depletion region is created. 2 4 U Draw circuit diagram of MOSFET amplifier with voltage divider biasing. 2 2 U State circuit diagram of dual input balanced output differential amplifier. iii) 2 4 U Sketch frequency response of CS amplifier and indicate low cut off iv) frequency, high cut off frequency and bandwidth. 4 U Draw circuit diagram of BJT as a switch. v) 2 4 U Define differential mode gain and Common mode for a differential vi) 2 5 amplifier. U vii) Explain miller effect? 2 6 U State advantages of multistage amplifiers. viii) 2 3 U Solve any four questions out of six. Q.2 16 Explain difference between silicon and zener diode? i) 4 1 U Explain concept of DC load line for the amplifier. ii) 4 3 U Draw circuit diagram of CS MOSFFET amplifier . Sketch input and output iii) waveform when 50 millivolts sine wave is applied as an input. What are 4 U its applications? A silicon PN junction has a reverse saturation current of I0 = 30 nA at iv) temperature of 300 degree Kelvin. Calculate junction current for applied 4 6 U voltage is a) 0.7 Volts forward bias b) 10 volts reverse bias.

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v)	State and explain diode current equation? State four applications of diode.	432	3	U
vi)	Draw and explain construction, working and characteristics of EMOSFET.	44	5	U
Q.3	Solve any two questions out of three.	16		
i)	Compare MOSFET and BJT amplifiers.	8	4	Ap
ii)	Explain drift and diffusion current, depletion and diffusion capacitance for PN junction?	8	6	U
iii)	What are different types of coupling methods used in multistage amplifiers? State its advantages, disadvantages and applications	8	5	U
Q.4	Solve any two questions out of three.	16		
i)	Draw circuit diagram and explain the operation two transistor current source	8	4	U
ii)	Draw small signal equivalent circuit of CS amplifier with unbypassed Rs and derive the equation of voltage gain, input and output resistance.	8	2	U
iii)	Determine low cut off frequency for the amplifier shown below Vcc=18 Volts, $\beta$ =100, V <sub>BE</sub> = 0.7V	8	2	Ap
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